Unit in mm

#### TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

# 2SC2510A

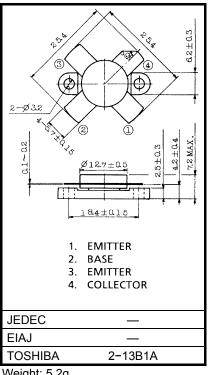
## 2~30MHz SSB LINEAR POWER AMPLIFIER APPLICATIONS (28V SUPPLY VOLTAGE USE)

Specified 28V, 28MHz Characteristics

Output Power  $: Po = 150W_{PEP} (Min.)$ Power Gain : Gp = 12.2dB (Min.)Collector Efficiency  $: \eta_C = 35\% \text{ (Min.)}$ Intermodulation Distortion: IMD = -30dB (Max.)

# **ABSOLUTE MAXIMUM RATINGS (Tc = 25°C)**

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	V <sub>CES</sub>	60	٧
Collector-Emitter Voltage	V <sub>CEO</sub>	35	V
Emitter-Base Voltage	V <sub>EBO</sub>	4	٧
Collector Current	Ic	20	Α
Collector Power Dissipation	PC	250	W
Junction Temperature	Tj	175	°C
Storage Temperature Range	T <sub>stg</sub>	-65~175	°C



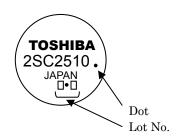
Weight: 5.2g

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **MARKING**

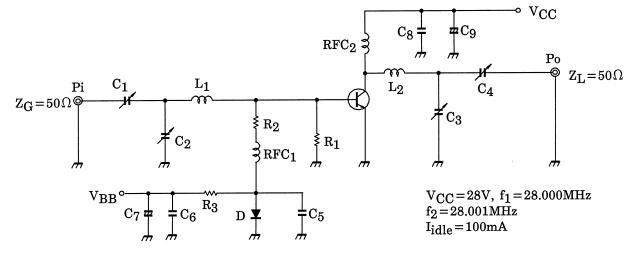


# ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Emitter Breakdown Voltage	V (BR) CEO	I <sub>C</sub> = 100mA, I <sub>B</sub> = 0	35	_	_	V
Collector-Emitter Breakdown Voltage	V (BR) CES	I <sub>C</sub> = 100mA, V <sub>EB</sub> = 0	55	_	_	V
Emitter-Base Breakdown Voltage	V (BR) EBO	I <sub>E</sub> = 1mA, I <sub>C</sub> = 0	4	_	_	V
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10A *	10	_	_	
Collector Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 28V, I <sub>E</sub> = 0 f = 1MHz	_	450	600	pF
Power Gain	Gp	V <sub>CC</sub> = 28V, f <sub>1</sub> = 28.000MHz, f <sub>2</sub> = 28.001MHz	12.2	13.3	_	dB
Input Power	Pi		_	7	9	W <sub>PEP</sub>
Collector Efficiency	η <sub>C</sub>	I <sub>idle</sub> = 100mA   Po = 150W <sub>PFP</sub> (Fig.)	35	_	_	%
Intermodulation Distortion	IMD		_	_	-30	dB
Series Equivalent Input Impedance	Z <sub>in</sub>	V <sub>CC</sub> = 28V, f <sub>1</sub> = 28.000MHz, f <sub>2</sub> = 28.001MHz,	_	1.4 -j0.9	_	Ω
Series Equivalent Output Impedance	Z <sub>out</sub>	Po = 150W <sub>PEP</sub>		2.3 -j0.9		Ω

<sup>\*</sup> Pulse Test: Pulse Width ≤ 100μs, Duty Cycle ≤ 3%

# Fig. Pi TEST CIRCUIT



C<sub>1</sub>, C<sub>2</sub> :  $7 \sim 150 \mathrm{pF}$  L<sub>1</sub> :  $\phi 0.8$  ENAMEL COATED COPPER WIRE, 14ID, 4T, 4P C<sub>3</sub>, C<sub>4</sub> :  $7 \sim 150 \mathrm{pF}$  2KWV L<sub>2</sub> :  $\phi 1.2$  ENAMEL COATED COPPER WIRE, 14ID, 3 1/2T, 3P C<sub>5</sub>, C<sub>6</sub> :  $0.022 \mu \mathrm{F}$  RFC<sub>1</sub> :  $\phi 0.8$  ENAMEL COATED COPPER WIRE, 10ID, 9T

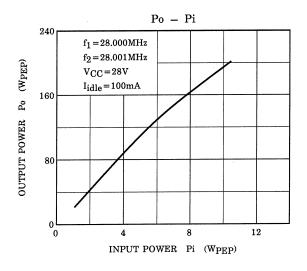
(Ferrite Core TDK K2)

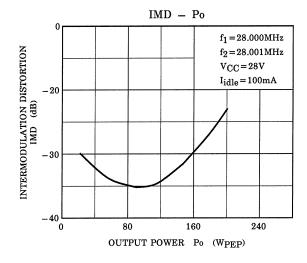
 $\begin{array}{cccc} {\rm C}_5, \ {\rm C}6 & : \ 0.022 \mu {\rm F} \\ {\rm C}_7 & : \ 47 \mu {\rm F} \ 10 {\rm WV} \end{array}$ 

 $_{\mathrm{C8}}$  :  $0.04\mu\mathrm{F}$  RFC $_{\mathrm{2}}$  :  $\phi$  0.8 ENAMEL COATED COPPER WIRE, 14ID, 20T

 $m C_9 = 100 \mu F 50WV \qquad R_1 = 10 \Omega \, (1W) \ R_2 = 2 \Omega \, (1/2W) \ R_2 = 10 \Omega \, (5W)$ 

 $\begin{array}{ccc} R_3 & : & 10\Omega (5W) \\ D & : & 1S1555 \end{array}$ 





### **CAUTION**

These are only typical curves and devices are not necessarily guaranteed at these curves.

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2007-11-01

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20070701-EN GENERAL

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